Diode Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Glass

# **Overall Length:**

Between 0.230 inches and 0.300 inches

# **Terminal Length:**

Between 1.000 inches and 1.500 inches

### **Overall Diameter:**

Between 0.092 inches and 0.130 inches

### Mounting Method:

Terminal

### **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

9.1 regulator voltage

## **Current Rating Per Characteristic:**

650.00 milliamperes forward current, average pascal

## **Power Rating Per Characteristic:**

400.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead

### **Specification Data:**

81349-mil-s-19500/437 government specification

Shelf Life:

N/a

# Unit Of Measure:

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### Demilitarization:

No

# Fiig:

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